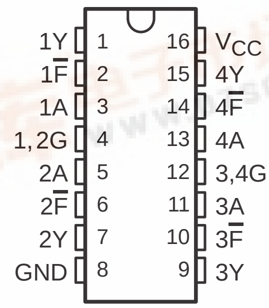
- **Meets or Exceeds the Requirements of IBM™ System 360/370 Input/Output Interface Specification GA22-6974-3**
- **Minimum Output Voltage of 3.11 V at I_{OH} = –59.3 mA**
- **Fault-Flag Circuit Output Signals Driver Output Fault**
- **Fault-Detection Current-Limit Circuit Minimizes Power Dissipation During a Fault Condition**
- **Dual Common Enable**
- **Individual Fault Flags**
- **Designed to Replace the MC3481**

D OR N PACKAGE
(TOP VIEW)



FUNCTION TABLE

INPUTS		OUTPUTS	
G	A	Y	$\overline{F}$
L	X	L	H
H	H	H	H
H	H	S	L

H = high level,
L = low level,
X = irrelevant,
S = shorted to ground

description

The SN75126 quadruple line driver is designed to meet the IBM 360/370 I/O specification A22-6974-3. The output voltage is 3.11 V minimum (at I_{OH} = –59.3 mA) over the recommended ranges of supply voltage (4.5 V to 5.95 V) and temperature. Driver outputs use a fault-detection current-limit circuit to allow high drive current but still minimize power dissipation when the output is shorted to ground. The SN75126 is compatible with standard TTL logic and supply voltages.

Fault-flag circuitry is designed to sense and signal a line short on any Y line. Upon detecting an output fault condition, the fault-flag circuit forces the driver output into a low state and signals a fault condition by causing the fault-flag output to go low.

The SN75126 can drive a 50-Ω load or a 90-Ω load as used in many I/O systems. Optimum performance can be achieved when the device is used with either the SN75128 or SN75129 line receivers. Also, see the SN751730 for new 360/370 interface designs.

The SN75126 is characterized for operation from 0°C to 70°C.

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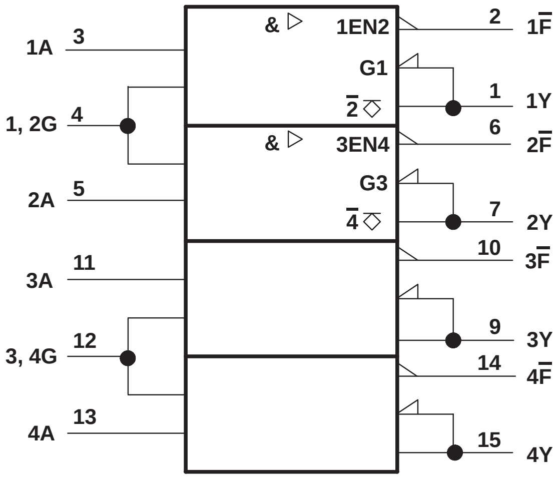
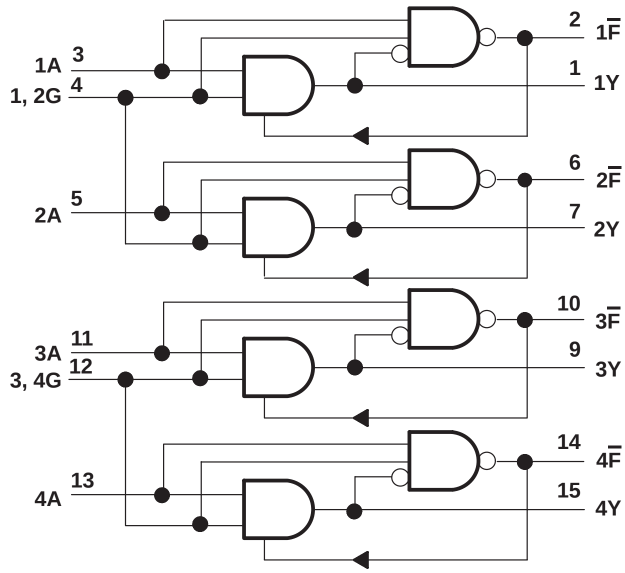
logic symbol†

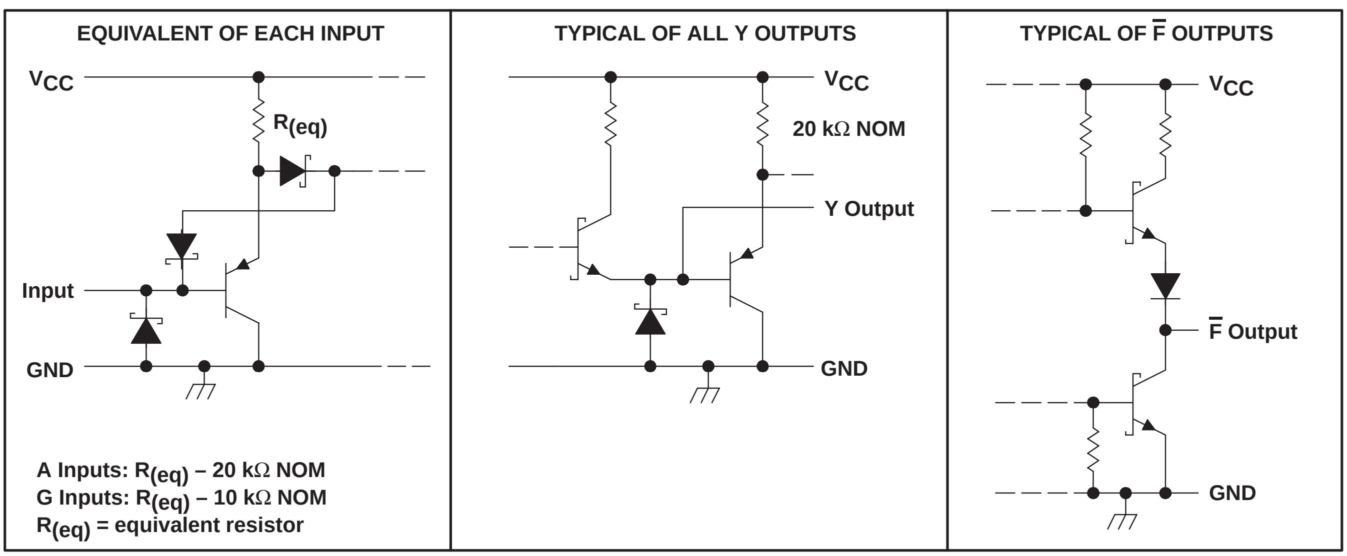


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



schematics of inputs and outputs



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC}	7 V
Input voltage, V_I	7 V
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A	0°C to 70°C
Storage temperature range, T_{stg}	– 65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING
D	950 mW	7.6 mW/°C	608 mW
N	1150 mW	9.2 mW/°C	736 mW

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}	4.5	5	5.95	V
High-level input voltage, V_{IH}	2			V
Low-level input voltage, V_{IL}			0.8	V
High-level output current, I_{OH}			–59.3	mA
Operating free-air temperature, T_A	0		70	°C

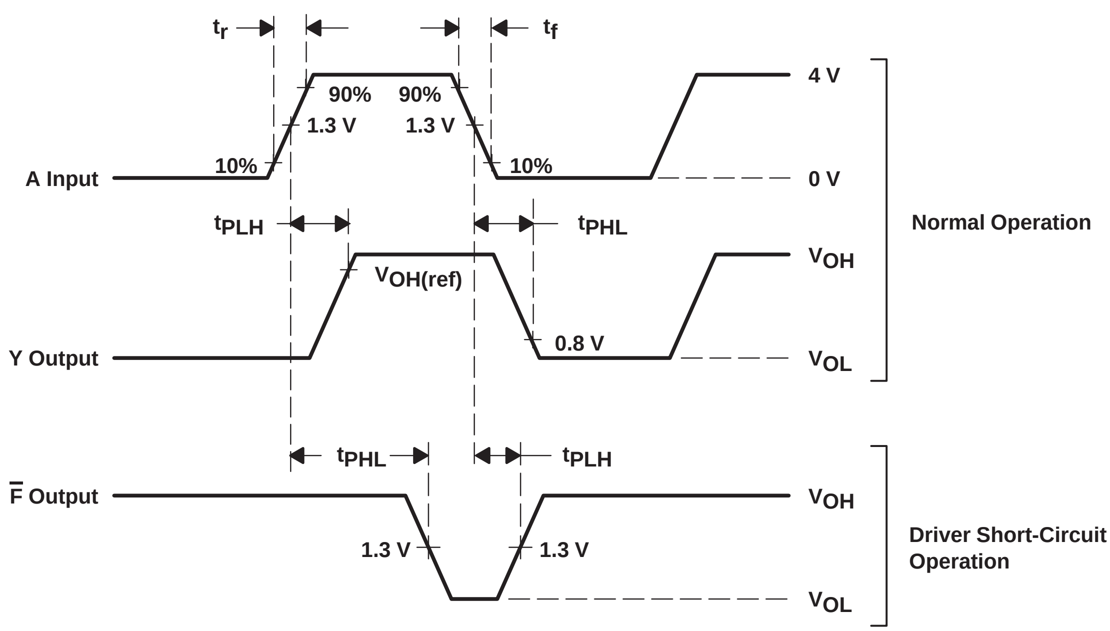
electrical characteristics over recommended operating free-air temperature range

PARAMETER			TEST CONDITIONS			MIN	MAX	UNIT
V_{IK}	Input clamp voltage	A,G	V_{CC} = 4.5 V,	I_I = –18 mA			–1.5	V
V_{OH}	High-level output voltage	Y	V_{CC} = 4.5 V,	I_{OH} = –59.3 mA,	V_{IH} = 2 V	3.11		V
		Y	V_{CC} = 5.25 V,	I_{OH} = –41 mA,	V_{IH} = 2 V	3.9		
		$\overline{F}$	V_{CC} = 4.5 V,	I_{OH} = –400 µA,	V_{IH} = 2 V	2.5		
V_{OL}	Low-level output voltage	Y	V_{CC} = 5.5 V,	I_{OL} = –240 µA,	V_{IL} = 0.8 V		0.15	V
		Y	V_{CC} = 5.95 V,	I_{OL} = –1 mA,	V_{IL} = 0.8 V		0.15	
		$\overline{F}$	V_{CC} = 4.5 V, V_{IH} = 2 V	I_{OL} = 8 mA,	Y at 0 V,		0.5	
$I_{O(off)}$	Off-state output current	Y	V_{CC} = 4.5 V,	V_I = 0,	V_O = 3.11 V		100	µA
		Y	V_{CC} = 0,	V_I = 0,	V_O = 3.11 V		200	
I_I	Input current	A	V_{CC} = 4.5 V,	V_I = 5.5 V			100	µA
		G					200	
I_{IH}	High-level input current	A	V_{CC} = 4.5 V,	V_I = 2.7 V			20	µA
		G					40	
I_{IL}	Low-level input current	A	V_{CC} = 5.95 V,	V_I = 0.4 V			–250	µA
		G					–500	
I_{OS}	Short-circuit output current	Y	V_{CC} = 5.5 V,	V_O = 0,	V_{IH} = 2.7 V		–5	mA
		$\overline{F}$	V_{CC} = 5.5 V,	V_O = 0		–15	–100	
		Y	V_{CC} = 5.95 V,	V_O = 0,	V_{IH} = 2.7 V		–5	
		$\overline{F}$	V_{CC} = 5.95 V,	V_O = 0		–15	–110	
I_{CCH}	Supply current, all outputs high		V_{CC} = 5.5 V,	No load,	V_{IH} = 2 V		70	mA
			V_{CC} = 5.95 V,	No load,	V_{IH} = 2 V		80	
I_{CCL}	Supply current, Y outputs low		V_{CC} = 5.5 V,	No load,	V_{IL} = 0.8 V		55	mA
			V_{CC} = 5.95 V,	No load,	V_{IL} = 0.8 V		70	

switching characteristics at T_A = 25°C

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	A	Y	V_{CC} = 4.5 V to 5.5 V, R_L = 50 Ω, C_L = 50 pF, $V_{OH(ref)}$ = 3.11 V, See Figures 1 and 2		40	ns
t_{PHL}	Propagation delay time, high- to low-level output					37	ns
$\frac{t_{PLH}}{t_{PHL}}$	Ratio of propagation delay times				0.3	3	
t_{PLH}	Propagation delay time, low- to high-level output	A	Y	V_{CC} = 5.25 V to 5.95 V, R_L = 90 Ω, C_L = 50 pF, $V_{OH(ref)}$ = 3.9 V, See Figures 1 and 2		45	ns
t_{PHL}	Propagation delay time, high- to low-level output					45	ns
t_{PLH}	Propagation delay time, low- to high-level output	A	$\overline{F}$	V_{CC} = 5 V, C_L = 15 pF, R_L = 2 kΩ, See Figures 1 and 2		60	ns
t_{PHL}	Propagation delay time, high- to low-level output					100	ns

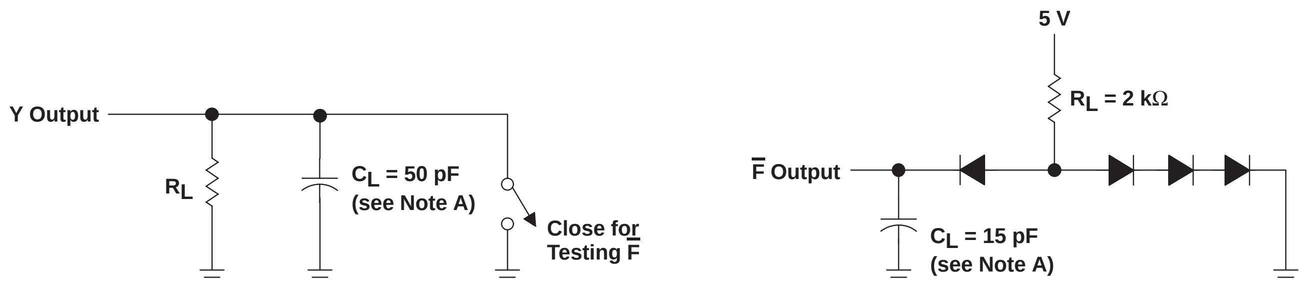
PARAMETER MEASUREMENT INFORMATION



NOTE: The input pulse is supplied by a generator having the following characteristics: PRR ≤ 1 MHz, duty cycle ≤ 50%, t_r ≤ 6 ns, t_f ≤ 6 ns, Z_O ≈ 50 Ω.

Figure 1. Input and Output Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION



NOTE A: C_L includes probe and stray capacitance.

Figure 2. Switching Characteristics Load Circuits

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